

Application Serial No.: 10/796,962
Reply to Office Action dated May 19, 2005

IN THE SPECIFICATION

Please replace the paragraph beginning at page 8, line 21, with the following rewritten paragraph:

Since the first standard cell 10 has less transistors than the second standard cell [[10]] 15, the effect of reducing the pattern area is greater in the former than in the latter. That is, if substrate contacts are formed in the first standard cell 10 which does not have many transistors and hence inherently occupies a small area, an increase in pattern area will become large.